Negative Voltage Regulators

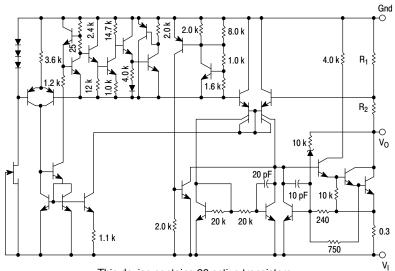
1.0 A

MC7900 Series

The MC7900 series of fixed output negative voltage regulators are intended as complements to the popular MC7800 series devices. These negative regulators are available in the same seven–voltage options as the MC7800 devices. In addition, one extra voltage option commonly employed in MECL systems is also available in the negative MC7900 series.

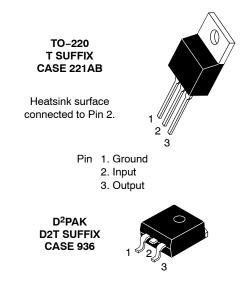
Available in fixed output voltage options from -5.0 V to -24 V, these regulators employ current limiting, thermal shutdown, and safe-area compensation – making them remarkably rugged under most operating conditions. With adequate heatsinking they can deliver output currents in excess of 1.0 A.

- No External Components Required
- Internal Thermal Overload Protection
- Internal Short Circuit Current Limiting
- Output Transistor Safe-Area Compensation
- Available in 2% Voltage Tolerance (See Ordering Information)
- Pb-Free Package May be Available. The G-Suffix Denotes a Pb-Free Lead Finish



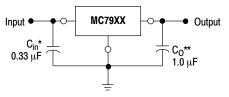
This device contains 26 active transistors.

Figure 1. Representative Schematic Diagram



Heatsink surface (shown as terminal 4 in case outline drawing) is connected to Pin 2.

STANDARD APPLICATION



A common ground is required between the input and the output voltages. The input voltage must remain typically 2.0 V above more negative even during the high point of the input ripple voltage.

- XX, These two digits of the type number indicate nominal voltage.
 - * C_{in} is required if regulator is located an appreciable distance from power supply filter.
- ** C_O improve stability and transient response.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 12 of this data sheet.

MAXIMUM RATINGS ($T_A = +25^{\circ}C$, unless otherwise noted.)

Rating	Symbol	Value	Unit
Input Voltage $(-5.0 \text{ V} \ge \text{V}_{\text{O}} \ge -18 \text{ V})$ (24 V)	VI	-35 -40	Vdc
Power Dissipation Case 221A $T_A = +25^{\circ}C$ Thermal Resistance, Junction-to-Ambient Thermal Resistance, Junction-to-Case Case 936 (D ² PAK)	Ρ _D θ _{JA} θ _{JC}	Internally Limited 65 5.0	W °C/W °C/W
$T_A = +25^{\circ}C$ Thermal Resistance, Junction-to-Ambient Thermal Resistance, Junction-to-Case	Ρ _D θ _{JA} θ _{JC}	Internally Limited 70 5.0	W ∘C/W ∘C/W
Storage Junction Temperature Range	T _{stg}	-65 to +150	°C
Junction Temperature	TJ	+150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. *This device series contains ESD protection and exceeds the following tests:

This device series contains ESD protection and exceeds the following tests Human Body Model 2000 V per MIL_STD_883, Method 3015 Machine Model Method 200 V

MC7905B, MC7905C ELECTRICAL CHARACTERISTICS (V_I = -10 V, I_O = 500 mA, Tlow* < T_J < $+125^{\circ}$ C, unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage ($T_J = +25^{\circ}C$)	Vo	-4.8	-5.0	-5.2	Vdc
Line Regulation (Note 1) (T _J = +25°C, I _O = 100 mA)	Reg _{line}				mV
$-7.0 \text{ Vdc} \ge \text{V}_1 \ge -25 \text{ Vdc}$		-	7.0	50	
$-8.0 \text{ Vdc} \ge V_1 \ge -12 \text{ Vdc}$		-	2.0	25	
$(T_J = +25^{\circ}C, I_O = 500 \text{ mA})$ -7.0 Vdc $\ge V_I \ge -25 \text{ Vdc}$		_	35	100	
$-8.0 \text{ Vdc} \ge V_1 \ge -12 \text{ Vdc}$		-	8.0	50	
Load Regulation, $T_J = +25^{\circ}C$ (Note 1)	Reg _{load}				mV
5.0 mA $\le I_0 \le 1.5$ A		-	11	100	
$250 \text{ mA} \le I_{O} \le 750 \text{ mA}$		-	4.0	50	
Output Voltage –7.0 Vdc \geq V_I \geq –20 Vdc, 5.0 mA \leq I_O \leq 1.0 A, P \leq 15 W	Vo	-4.75	-	-5.25	Vdc
Input Bias Current (T _J = +25°C)	I _{IB}	-	4.3	8.0	mA
Input Bias Current Change	ΔI_{IB}				mA
$-7.0 \text{ Vdc} \ge V_1 \ge -25 \text{ Vdc}$		-	-	1.3	
$5.0 \text{ mA} \le I_0 \le 1.5 \text{ A}$		-	-	0.5	
Output Noise Voltage (T _A = +25°C, 10 Hz \leq f \leq 100 kHz)	Vn	-	40	-	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	70	-	dB
Dropout Voltage	V _I –V _O				Vdc
$I_{O} = 1.0 \text{ A}, \text{ T}_{J} = +25^{\circ}\text{C}$		-	1.3	-	
Average Temperature Coefficient of Output Voltage	$\Delta V_O / \Delta T$				mV/°C
$I_{O} = 5.0 \text{ mA}, \text{ Tlow}^* \le T_{J} \le +125^{\circ}\text{C}$		-	-1.0	-	

 Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

*Tlow = -40° C for MC7905B and Tlow = 0° C for MC7905C.

MC7905AC

ELECTRICAL CHARACTERISTICS (V_I = -10 V, I_O = 500 mA, 0°C < T_J < +125°C, unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage ($T_J = +25^{\circ}C$)	Vo	-4.9	-5.0	-5.1	Vdc
$ \begin{array}{l} \mbox{Line Regulation (Note 2)} \\ -8.0 \mbox{ Vdc} \geq V_I \geq -12 \mbox{ Vdc}; \ I_O = 1.0 \mbox{ A}, \ T_J = +25^\circ C \\ -8.0 \mbox{ Vdc} \geq V_I \geq -12 \mbox{ Vdc}; \ I_O = 1.0 \mbox{ A} \\ -7.5 \mbox{ Vdc} \geq V_I \geq -25 \mbox{ Vdc}; \ I_O = 500 \mbox{ mA} \\ -7.0 \mbox{ Vdc} \geq V_I \geq -20 \mbox{ Vdc}; \ I_O = 1.0 \mbox{ A}, \ T_J = +25^\circ C \end{array} $	Reg _{line}	- - -	2.0 7.0 7.0 6.0	25 50 50 50	mV
Load Regulation (Note 2) 5.0 mA $\leq I_O \leq$ 1.5 A, T _J = +25°C 250 mA $\leq I_O \leq$ 750 mA 5.0 mA $\leq I_O \leq$ 1.0 A	Reg _{load}	- - -	11 4.0 9.0	100 50 100	mV
Output Voltage –7.5 Vdc \geq V_l \geq –20 Vdc, 5.0 mA \leq I_O \leq 1.0 A, P \leq 15 W	V _O	-4.80	_	-5.20	Vdc
Input Bias Current	I _{IB}	-	4.4	8.0	mA
Input Bias Current Change $-7.5 \text{ Vdc} \ge V_I \ge -25 \text{ Vdc}$ $5.0 \text{ mA} \le I_O \le 1.0 \text{ A}$ $5.0 \text{ mA} \le I_O \le 1.5 \text{ A}, T_J = +25^{\circ}\text{C}$	ΔI _{IB}	- - -	- - -	1.3 0.5 0.5	mA
Output Noise Voltage (T _A = +25°C, 10 Hz \leq f \leq 100 kHz)	Vn	_	40	-	μV
Ripple Rejection (I _O = mA, f = 120 Hz)	RR	_	70	-	dB
Dropout Voltage ($I_0 = 1.0 \text{ A. } T_J = +25^{\circ}\text{C}$)	V _I –V _O	_	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage I_{O} = 5.0 mA, 0°C \leq T_{J} \leq +125°C	$\Delta V_{O} / \Delta T$	-	-1.0	-	mV/°C

MC7905.2C

ELECTRICAL CHARACTERISTICS (V_I = -10 V, I_O = 500 mA, 0°C < T_J < +125°C, unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage ($T_J = +25^{\circ}C$)	V _O	-5.0	-5.2	-5.4	Vdc
Line Regulation (Note 2) (T _J = +25°C, I _O = 100 mA)	Reg _{line}				mV
$-7.2 \text{ Vdc} \ge V_1 \ge -25 \text{ Vdc}$ -8.0 Vdc $\ge V_1 \ge -12 \text{ Vdc}$			8.0 2.2	52 27	
$ (T_J = +25^{\circ}C, I_O = 500 \text{ mA}) $			37 8.5	105 52	
Load Regulation, T_J = +25°C (Note 2) 5.0 mA \le I _O \le 1.5 A 250 mA \le I _O \le 750 mA	Reg _{load}		12 4.5	105 52	mV
Output Voltage –7.2 Vdc \geq V $_{I}$ \geq –20 Vdc, 5.0 mA \leq I $_{O}$ \leq 1.0 A, P \leq 15 W	Vo	-4.95	_	-5.45	Vdc
Input Bias Current (T _J = +25°C)	I _{IB}	-	4.3	8.0	mA
Input Bias Current Change $-7.2 \text{ Vdc} \ge V_1 \ge -25 \text{ Vdc}$ $5.0 \text{ mA} \le I_0 \le 1.5 \text{ A}$	Δl _{IB}			1.3 0.5	mA
Output Noise Voltage (T _A = +25°C, 10 Hz \leq f \leq 100 kHz)	V _n	-	42	-	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	68	-	dB
Dropout Voltage (I _O = 1.0 A, T_J = +25°C)	V _I –V _O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage $I_O = 5.0$ mA, $0^\circ C \leq T_J \leq +125^\circ C$	$\Delta V_{O} / \Delta T$	-	-1.0	_	mV/°C

 Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

MC7906C

 $\textbf{ELECTRICAL CHARACTERISTICS}~(V_I = -11~V,~I_O = 500~mA,~0^{\circ}C < T_J < +125^{\circ}C,~unless~otherwise~noted.)$

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage ($T_J = +25^{\circ}C$)	Vo	-5.75	-6.0	-6.25	Vdc
Line Regulation (Note 3) $(T_J = +25^{\circ}C, I_O = 100 \text{ mA})$	Reg _{line}				mV
$-8.0 \text{ Vdc} \ge V_1 \ge -25 \text{ Vdc}$ $-9.0 \text{ Vdc} \ge V_1 \ge -13 \text{ Vdc}$			9.0 3.0	60 30	
			43 10	120 60	
Load Regulation, T_J = +25°C (Note 3) 5.0 mA \le I _O \le 1.5 A 250 mA \le I _O \le 750 mA	Reg _{load}	- -	13 5.0	120 60	mV
Output Voltage $-8.0~Vdc \geq V_l \geq -21~Vdc,~5.0~mA \leq I_O \leq 1.0~A,~P \leq 15~W$	Vo	-5.7	_	-6.3	Vdc
Input Bias Current (T _J = +25°C)	I _{IB}	-	4.3	8.0	mA
Input Bias Current Change $-8.0 \text{ Vdc} \ge V_I \ge -25 \text{ Vdc}$ $5.0 \text{ mA} \le I_O \le 1.5 \text{ A}$	ΔI _{IB}			1.3 0.5	mA
Output Noise Voltage (T _A = +25°C, 10 Hz \leq f \leq 100 kHz)	V _n	-	45	-	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	65	-	dB
Dropout Voltage ($I_O = 1.0 \text{ A}, T_J = +25^{\circ}\text{C}$)	V _I –V _O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage I_{O} = 5.0 mA, 0°C \leq T_{J} \leq +125°C	$\Delta V_O / \Delta T$	_	-1.0	_	mV/°C

MC7908C

ELECTRICAL CHARACTERISTICS (V_I = -14 V, I_O = 500 mA, 0°C < T_J < +125°C, unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	-7.7	-8.0	-8.3	Vdc
Line Regulation (Note 3) (T _J = +25°C, I _O = 100 mA)	Reg _{line}				mV
$-10.5 \text{ Vdc} \ge V_I \ge -25 \text{ Vdc}$ $-11 \text{ Vdc} \ge V_I \ge -17 \text{ Vdc}$			12 5.0	80 40	
$(T_J = +25^{\circ}C, I_O = 500 \text{ mA})$ -10.5 Vdc $\ge V_I \ge -25 \text{ Vdc}$ -11 Vdc $\ge V_I \ge -17 \text{ Vdc}$			50 22	160 80	
Load Regulation, T_J = +25°C (Note 3) 5.0 mA $\leq I_O \leq$ 1.5 A 250 mA $\leq I_O \leq$ 750 mA	Reg _{load}		26 9.0	160 80	mV
Output Voltage –10.5 Vdc \geq V_I \geq –23 Vdc, 5.0 mA \leq I_O \leq 1.0 A, P \leq 15 W	V _O	-7.6	_	-8.4	Vdc
Input Bias Current (T _J = +25°C)	I _{IB}	-	4.3	8.0	mA
Input Bias Current Change $-10.5 \text{ Vdc} \ge V_I \ge -25 \text{ Vdc}$ $5.0 \text{ mA} \le I_O \le 1.5 \text{ A}$	ΔI _{IB}			1.0 0.5	mA
Output Noise Voltage (T_A = +25°C, 10 Hz \leq f \leq 100 kHz)	V _n	-	52	-	μV
Ripple Rejection (I_0 = 20 mA, f = 120 Hz)	RR	-	62	-	dB
Dropout Voltage (I _O = 1.0 A, T_J = +25°C)	V _I –V _O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage I_O = 5.0 mA, 0°C \leq T_J \leq +125°C	$\Delta V_O / \Delta T$	-	-1.0	-	mV/°C

 Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

MC7912B, MC7912C

ELECTRICAL CHARACTERISTICS (V_I = -19 V, I_O = 500 mA, Tlow* < T_J < +125°C, unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage ($T_J = +25^{\circ}C$)	Vo	-11.5	-12	-12.5	Vdc
Line Regulation (Note 4) ($T_J = +25^{\circ}C$, $I_O = 100$ mA)	Reg _{line}				mV
$-14.5 \text{ Vdc} \ge V_1 \ge -30 \text{ Vdc}$ $-16 \text{ Vdc} \ge V_1 \ge -22 \text{ Vdc}$			13 6.0	120 60	
$ \begin{array}{l} (T_J = +25^{\circ}C, \ I_O = 500 \ \text{mA}) \\ -14.5 \ \text{Vdc} \geq V_I \geq -30 \ \text{Vdc} \\ -16 \ \text{Vdc} \geq V_I \geq -22 \ \text{Vdc} \end{array} $			55 24	240 120	
Load Regulation, T_J = +25°C (Note 4) 5.0 mA $\leq I_O \leq$ 1.5 A 250 mA $\leq I_O \leq$ 750 mA	Reg _{load}		46 17	240 120	mV
Output Voltage –14.5 Vdc \geq VI \geq –27 Vdc, 5.0 mA \leq I_O \leq 1.0 A, P \leq 15 W	V _O	-11.4	_	-12.6	Vdc
Input Bias Current ($T_J = +25^{\circ}C$)	I _{IB}	-	4.4	8.0	mA
Input Bias Current Change $-14.5 \text{ Vdc} \ge V_I \ge -30 \text{ Vdc}$ $5.0 \text{ mA} \le I_O \le 1.5 \text{ A}$	Δl _{IB}			1.0 0.5	mA
Output Noise Voltage (T _A = +25°C, 10 Hz \leq f \leq 100 kHz)	Vn	-	75	-	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	61	-	dB
Dropout Voltage ($I_0 = 1.0 \text{ A}, T_J = +25^{\circ}\text{C}$)	V _I –V _O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage I_{O} = 5.0 mA, Tlow* $\leq T_{J} \leq$ +125°C	$\Delta V_{O} / \Delta T$	_	-1.0	_	mV/°C

MC7912AC

 $\label{eq:linear} \textbf{ELECTRICAL CHARACTERISTICS} ~ (V_I = -19 ~ V, ~ I_O = 500 ~ mA, ~ Tlow^* < T_J < +125^{\circ}C, ~ unless ~ otherwise ~ noted.)$

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	-11.75	-12	-12.25	Vdc
$ \begin{array}{l} \mbox{Line Regulation (Note 4)} \\ -16 \mbox{ Vdc} \geq V_I \geq -22 \mbox{ Vdc}; I_O = 1.0 A, T_J = +25^\circ C \\ -16 \mbox{ Vdc} \geq V_I \geq -22 \mbox{ Vdc}; I_O = 1.0 A \\ -14.8 \mbox{ Vdc} \geq V_I \geq -30 \mbox{ Vdc}; I_O = 500 mA \\ -14.5 \mbox{ Vdc} \geq V_I \geq -27 \mbox{ Vdc}; I_O = 1.0 A, T_J = +25^\circ C \end{array} $	Reg _{line}	- - - -	6.0 24 24 13	60 120 120 120	mV
Load Regulation (Note 4) 5.0 mA \le I _O \le 1.5 A, T _J = +25°C 250 mA \le I _O \le 750 mA 5.0 mA \le I _O \le 1.0 A	Reg _{load}	- - -	46 17 35	150 75 150	mV
Output Voltage –14.8 Vdc \geq VI \geq –27 Vdc, 5.0 mA \leq I_O \leq 1.0 A, P \leq 15 W	Vo	-11.5	-	-12.5	Vdc
Input Bias Current	I _{IB}	-	4.4	8.0	mA
Input Bias Current Change $-15 \text{ Vdc} \ge V_I \ge -30 \text{ Vdc}$ $5.0 \text{ mA} \le I_O \le 1.0 \text{ A}$ $5.0 \text{ mA} \le I_O \le 1.5 \text{ A}, T_J = +25^{\circ}\text{C}$	ΔI _{IB}	- - -	- - -	0.8 0.5 0.5	mA
Output Noise Voltage (T _A = +25°C, 10 Hz \leq f \leq 100 kHz)	Vn	-	75	-	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	61	-	dB
Dropout Voltage ($I_0 = 1.0 \text{ A}, T_J = +25^{\circ}\text{C}$)	V _I –V _O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage $I_O = 5.0~mA,~Tlow^* \leq T_J \leq +125^\circ C$	$\Delta V_O / \Delta T$	_	-1.0	_	mV/°C

 Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

*Tlow = -40° C for MC7912B and Tlow = 0° C for MC7912C.

MC7915B, MC7915C

ELECTRICAL CHARACTERISTICS ($V_I = -23 \text{ V}$, $I_O = 500 \text{ mA}$, Tlow* < T_J < +125°C, unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = $+25^{\circ}$ C)	Vo	-14.4	-15	-15.6	Vdc
Line Regulation (Note 5) $(T_J = +25^{\circ}C, I_O = 100 \text{ mA})$ $-17.5 \text{ Vdc} \ge V_I \ge -30 \text{ Vdc}$	Reg _{line}	_	14	150	mV
$-20 \text{ Vdc} \ge V_I \ge -26 \text{ Vdc}$ (T _J = +25°C, I _O = 500 mA)		-	6.0	75	
$\begin{array}{l} -17.5 \ \text{Vdc} \geq \text{V}_{\text{I}} \geq -30 \ \text{Vdc} \\ -20 \ \text{Vdc} \geq \text{V}_{\text{I}} \geq -26 \ \text{Vdc} \end{array}$			57 27	300 150	
Load Regulation, T_J = +25°C (Note 5) 5.0 mA \le I _O \le 1.5 A 250 mA \le I _O \le 750 mA	Reg _{load}		68 25	300 150	mV
Output Voltage –17.5 Vdc \geq VI \geq –30 Vdc, 5.0 mA \leq I_O \leq 1.0 A, P \leq 15 W	Vo	-14.25	_	-15.75	Vdc
Input Bias Current ($T_J = +25^{\circ}C$)	I _{IB}	-	4.4	8.0	mA
Input Bias Current Change $-17.5 \text{ Vdc} \ge V_I \ge -30 \text{ Vdc}$ $5.0 \text{ mA} \le I_O \le 1.5 \text{ A}$	ΔI _{IB}		- -	1.0 0.5	mA
Output Noise Voltage (T _A = +25°C, 10 Hz \leq f \leq 100 kHz)	V _n	-	90	-	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	60	-	dB
Dropout Voltage (I_0 = 1.0 A, T_J = +25°C)	V _I –V _O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage I_{O} = 5.0 mA, Tlow* $\leq T_{J} \leq$ +125 $^{\circ}C$	$\Delta V_{O} / \Delta T$	-	-1.0	_	mV/°C

MC7915AC

 $\label{eq:linear} \textbf{ELECTRICAL CHARACTERISTICS} ~ (V_I = -23~V,~I_O = 500~mA,~Tlow^* < T_J < +125^{\circ}C,~unless~otherwise~noted.)$

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage ($T_J = +25^{\circ}C$)	Vo	-14.7	-15	-15.3	Vdc
$ \begin{array}{l} \mbox{Line Regulation (Note 5)} \\ -20 \mbox{ Vdc} \geq V_I \geq -26 \mbox{ Vdc}, I_O = 1.0 A, T_J = +25^\circ C \\ -20 \mbox{ Vdc} \geq V_I \geq -26 \mbox{ Vdc}, I_O = 1.0 A, \\ -17.9 \mbox{ Vdc} \geq V_I \geq -30 \mbox{ Vdc}, I_O = 500 mA \\ -17.5 \mbox{ Vdc} \geq V_I \geq -30 \mbox{ Vdc}, I_O = 1.0 A, T_J = +25^\circ C \end{array} $	Reg _{line}	- - - -	27 57 57 57	75 150 150 150	mV
Load Regulation (Note 5) 5.0 mA \le I _O \le 1.5 A, T _J = +25°C 250 mA \le I _O \le 750 mA 5.0 mA \le I _O \le 1.0 A	Reg _{load}	- - -	68 25 40	150 75 150	mV
Output Voltage –17.9 Vdc \geq VI \geq –30 Vdc, 5.0 mA \leq I_O \leq 1.0 A, P \leq 15 W	Vo	-14.4	-	-15.6	Vdc
Input Bias Current	I _{IB}	-	4.4	8.0	mA
Input Bias Current Change $-17.5 \text{ Vdc} \ge V_I \ge -30 \text{ Vdc}$ $5.0 \text{ mA} \le I_O \le 1.0 \text{ A}$ $5.0 \text{ mA} \le I_O \le 1.5 \text{ A}, T_J = +25^{\circ}\text{C}$	ΔI _{IB}	- - -	- - -	0.8 0.5 0.5	mA
Output Noise Voltage (T _A = +25°C, 10 Hz \leq f \leq 100 kHz)	Vn	-	90	-	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	60	-	dB
Dropout Voltage (I _O = 1.0 A, T_J = +25°C)	V _I –V _O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage $I_O = 5.0~mA,~Tlow^* \leq T_J \leq +125^\circ C$	$\Delta V_O / \Delta T$	_	-1.0	_	mV/°C

 Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

*Tlow = -40° C for MC7915B and Tlow = 0° C for MC7915C.

MC7918C

 $\textbf{ELECTRICAL CHARACTERISTICS}~(V_I = -27~V,~I_O = 500~mA,~0^{\circ}C < T_J < +125^{\circ}C,~unless~otherwise~noted.)$

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage ($T_J = +25^{\circ}C$)	Vo	-17.3	-18	-18.7	Vdc
Line Regulation (Note 6) $(T_J = +25^{\circ}C, I_Q = 100 \text{ mA})$	Reg _{line}				mV
$-21 \text{ Vdc} \ge V_1 \ge -33 \text{ Vdc}$ $-24 \text{ Vdc} \ge V_1 \ge -30 \text{ Vdc}$			25 10	180 90	
$ (T_J = +25^{\circ}C, I_O = 500 \text{ mA}) -21 \text{ Vdc} \ge V_I \ge -33 \text{ Vdc} -24 \text{ Vdc} \ge V_I \ge -30 \text{ Vdc} $		-	90 50	360 180	
Load Regulation, T_J = +25°C (Note 6) 5.0 mA $\leq I_O \leq$ 1.5 A 250 mA $\leq I_O \leq$ 750 mA	Reg _{load}		110 55	360 180	mV
Output Voltage –21 Vdc \geq V _I \geq –33 Vdc, 5.0 mA \leq I _O \leq 1.0 A, P \leq 15 W	Vo	-17.1	_	-18.9	Vdc
Input Bias Current ($T_J = +25^{\circ}C$)	I _{IB}	-	4.5	8.0	mA
Input Bias Current Change -21 Vdc \ge V ₁ \ge -33 Vdc 5.0 mA \le I ₀ \le 1.5 A	ΔI _{IB}			1.0 0.5	mA
Output Noise Voltage (T _A = +25°C, 10 Hz \leq f \leq 100 kHz)	Vn	-	110	-	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	59	-	dB
Dropout Voltage (I_0 = 1.0 A, T_J = +25°C)	V _I –V _O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage I_{O} = 5.0 mA, 0°C \leq T_{J} \leq +125°C	$\Delta V_0 / \Delta T$	-	-1.0	_	mV/°C

MC7924B, MC7924C

ELECTRICAL CHARACTERISTICS (V_I = -33 V, I_O = 500 mA, Tlow* < T_J < $+125^{\circ}$ C, unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage ($T_J = +25^{\circ}C$)	Vo	-23	-24	-25	Vdc
Line Regulation (Note 6) (T _J = +25°C, I _O = 100 mA)	Reg _{line}				mV
$-27 \text{ Vdc} \ge V_1 \ge -38 \text{ Vdc}$ $-30 \text{ Vdc} \ge V_1 \ge -36 \text{ Vdc}$			31 14	240 120	
			118 70	470 240	
Load Regulation, T _J = +25°C (Note 6) 5.0 mA \leq I _O \leq 1.5 A 250 mA \leq I _O \leq 750 mA	Reg _{load}		150 85	480 240	mV
Output Voltage –27 Vdc \geq VI \geq –38 Vdc, 5.0 mA \leq IO \leq 1.0 A, P \leq 15 W	Vo	-22.8	_	-25.2	Vdc
Input Bias Current ($T_J = +25^{\circ}C$)	I _{IB}	-	4.6	8.0	mA
Input Bias Current Change $-27 \text{ Vdc} \ge V_I \ge -38 \text{ Vdc}$ $5.0 \text{ mA} \le I_O \le 1.5 \text{ A}$	ΔI_{IB}			1.0 0.5	mA
Output Noise Voltage (T _A = +25°C, 10 Hz \leq f \leq 100 kHz)	Vn	-	170	-	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	56	-	dB
Dropout Voltage (I _O = 1.0 A, T_J = +25°C)	V _I –V _O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage $I_O = 5.0~mA,~Tlow^* \leq T_J \leq +125^\circ C$	$\Delta V_{O} / \Delta T$	-	-1.0	_	mV/°C

 Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

*Tlow = -40° C for MC7924B and Tlow = 0° C for MC7924C.

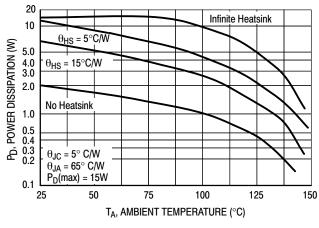


Figure 2. Worst Case Power Dissipation as a Function of Ambient Temperature

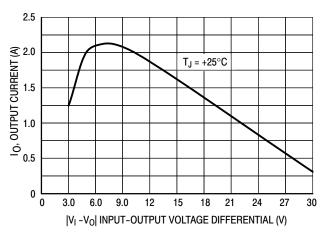
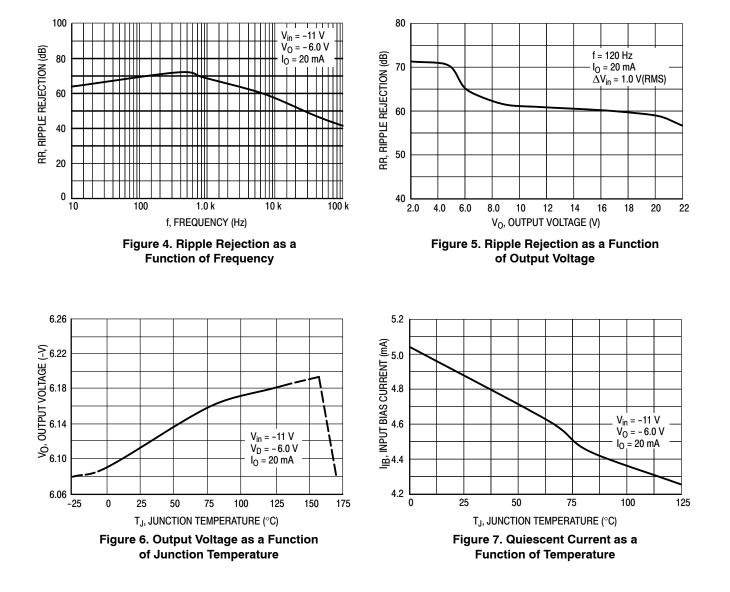


Figure 3. Peak Output Current as a Function of Input–Output Differential Voltage



APPLICATIONS INFORMATION

Design Considerations

The MC7900 Series of fixed voltage regulators are designed with Thermal overload Protection that shuts down the circuit when subjected to an excessive power overload condition. Internal Short Circuit Protection that limits the maximum current the circuit will pass, and Output Transistor Safe–Area Compensation that reduces the output short circuit current as the voltage across the pass transistor is increased.

In many low current applications, compensation capacitors are not required. However, it is recommended that the regulator input be bypassed with a capacitor if the regulator is connected to the power supply filter with long wire lengths, or if the output load capacitance is large. An input bypass capacitor should be selected to provide good high-frequency characteristics to insure stable operation under all load conditions. A 0.33 µF or larger tantalum, mylar, or other capacitor having low internal impedance at high frequencies should be chosen. The capacitor chosen should have an equivalent series resistance of less than 0.7Ω . The bypass capacitor should be mounted with the shortest possible leads directly across the regulators input terminals. Normally good construction techniques should be used to minimize ground loops and lead resistance drops since the regulator has no external sense lead. Bypassing the output is also recommended.

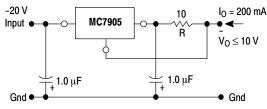


Figure 8. Current Regulator

The MC7905, –5.0 V regulator can be used as a constant current source when connected as above. The output current is the sum of resistor R current and quiescent bias current as follows:

$$I_{O} = \frac{5.0 \text{ V}}{\text{R}} + I_{B}$$

The quiescent current for this regulator is typically 4.3 mA. The 5.0 V regulator was chosen to minimize dissipation and to allow the output voltage to operate to within 6.0 V below the input voltage.

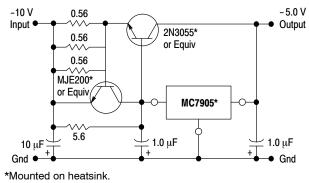
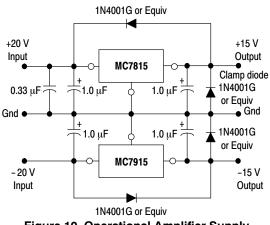


Figure 9. Current Boost Regulator (-5.0 V @ 4.0 A, with 5.0 A Current Limiting)

When a boost transistor is used, short circuit currents are equal to the sum of the series pass and regulator limits, which are measured at 3.2 A and 1.8 A respectively in this case. Series pass limiting is approximately equal to 0.6 V/R_{SC}. Operation beyond this point to the peak current capability of the MC7905C is possible if the regulator is mounted on a heatsink; otherwise thermal shutdown will occur when the additional load current is picked up by the regulator.





The MC7815 and MC7915 positive and negative regulators may be connected as shown to obtain a dual power supply for operational amplifiers. A clamp diode should be used at the output of the MC7815 to prevent potential latch-up problems whenever the output of the positive regulator (MC7815) is drawn below ground with an output current greater than 200 mA.

Protection Diodes

When external capacitors are used with MC7900 series regulator it is sometimes necessary to add protection diodes to prevent the capacitors from discharging through low current points into the regulator or from output polarity reversals. Generally, no protection diode is required for values of output capacitance less then 10μ F. Figure 11 shows the MC7915 with the recommended protection diodes.

• Opposite Polarity Protection

Diode D1 protects the regulator from output polarity reversals during startup, power off and short-circuit operation.

• Reverse-bias Protection

Diode D2 prevents output capacitor from discharging thru the MC7915 during an input short circuit or fast switch off of power supply.

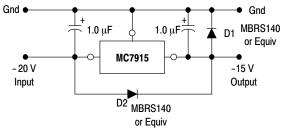


Figure 11. Protection Diodes

DEFINITIONS

Line Regulation – The change in output voltage for a change in the input voltage. The measurement is made under conditions of low dissipation or by using pulse techniques such that the average chip temperature is not significantly affected.

Load Regulation – The change in output voltage for a change in load current at constant chip temperature.

Maximum Power Dissipation – The maximum total device dissipation for which the regulator will operate within specifications.

Input Bias Current – That part of the input current that is not delivered to the load.

Output Noise Voltage – The rms AC voltage at the output, with constant load and no input ripple, measured over a specified frequency range.

Long Term Stability – Output voltage stability under accelerated life test conditions with the maximum rated voltage listed in the devices' electrical characteristics and maximum power dissipation.

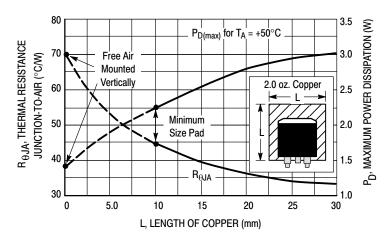


Figure 12. D²PAK Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

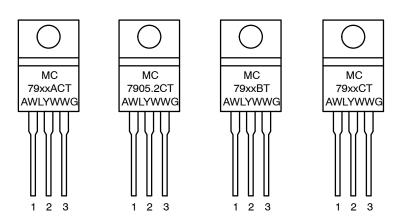
ORDERING INFORMATION

Device	Nominal Output Voltage	Output Voltage Tolerance	Package	Operating Temperature Range	Shipping†
MC7905ACD2TR4G	–5.0 V	2%	D ² PAK (Pb–Free)	$T_J = 0^{\circ}C$ to +125°C	800 Tape & Reel
MC7905BTG		4%	TO-220 (Pb-Free)	$T_J = -40^{\circ}C$ to $+125^{\circ}C$	50 Units/Rail
MC7905CTG			TO-220 (Pb-Free)	$T_J = 0^{\circ}C$ to +125°C	50 Units/Rail
MC7906CTG	-6.0 V	4%	TO-220 (Pb-Free)	$T_J = 0^{\circ}C$ to +125°C	50 Units/Rail
MC7912ACTG	–12 V	2%	TO-220 (Pb-Free)	$T_J = 0^{\circ}C$ to +125°C	50 Units/Rail
MC7912BD2TR4G		4%	D ² PAK (Pb–Free)	$T_J = -40^{\circ}C$ to $+125^{\circ}C$	800 Tape & Reel
MC7912BTG			TO-220 (Pb-Free)		50 Units/Rail
MC7912CTG			TO-220 (Pb-Free)	$T_J = 0^{\circ}C$ to +125°C	50 Units/Rail
MC7915ACD2TG	– 15 V	2%	D ² PAK (Pb–Free)	$T_J = 0^{\circ}C$ to +125°C	50 Units/Rail
MC7915ACD2TR4G			D ² PAK (Pb–Free)		800 Tape & Reel
MC7915ACTG			TO-220 (Pb-Free)		50 Units/Rail
MC7915BTG		4%	TO-220 (Pb-Free)	$T_J = -40^{\circ}C$ to $+125^{\circ}C$	50 Units/Rail
MC7915BD2TR4G			D ² PAK (Pb–Free)		800 Tape & Reel
MC7915CD2TR4G	1		D ² PAK (Pb–Free)	$T_J = 0^{\circ}C$ to +125°C	800 Tape & Reel
MC7915CTG	1		TO–220 (Pb–Free)		50 Units/Rail
MC7918CTG			TO-220 (Pb-Free)		50 Units/Rail

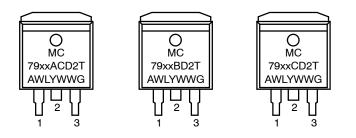
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

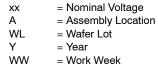
MARKING DIAGRAMS

TO-220 T SUFFIX CASE 221AB



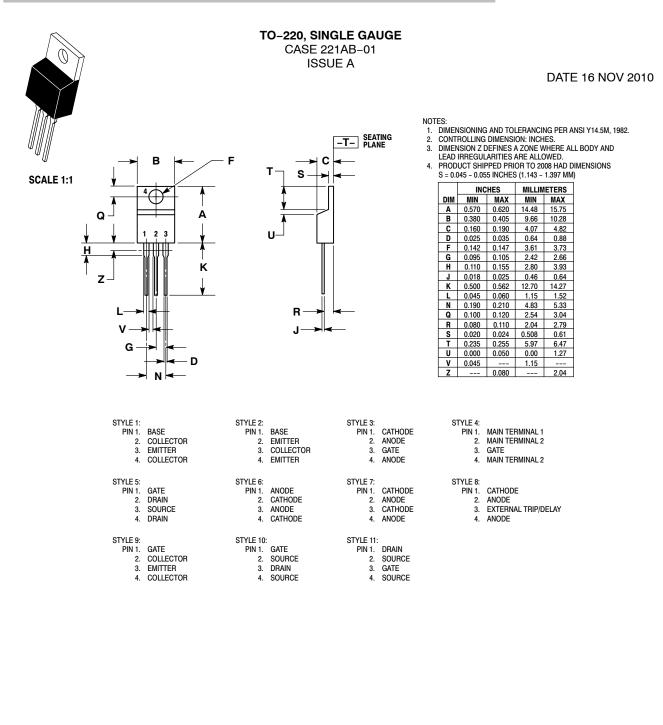
D²PAK D2T SUFFIX CASE 936





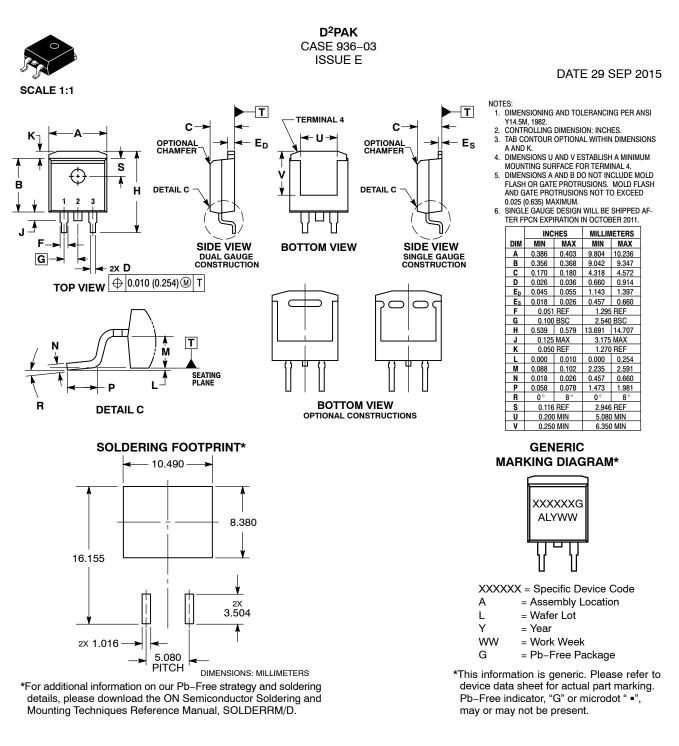
G = Pb–Free Device





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